

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 246155US2SRD		SERIAL NO. 10/726705 <u>New Application</u>	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Masato KOYAMA, et al.			
				FILING DATE <u>Herewith 12/4/03</u>		GROUP <u>2811</u>	
				U.S. PATENT DOCUMENTS			
EXAMINER INITIAL	AA	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
	AO						
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
<u>SR</u>	AW	M. R. VISOKAY, et al., "APPLICATION OF HfSiON AS A GATE DIELECTRIC MATERIAL", Applied Physics Letters, Volume 80, Number 17, April 29, 2002, Pages 3183-3185					
<u>SR</u>	AX	R. A. McKEE, et al., "PHYSICAL STRUCTURE AND INVERSION CHARGE AT A SEMICONDUCTOR INTERFACE WITH A CRYSTALLINE OXIDE", Science Magazine, Vol. 293, July 20, 2001, Pages 468-471					
	AY						
	AZ						
Examiner <u>Shoemaker</u>					<input type="checkbox"/> Additional References sheet(s) attached Date Considered <u>12/06/04</u>		
<small>*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</small>							